

Data sheet acquired from Harris Semiconductor SCHS174B

CD54HC273, CD74HC273, CD54HCT273

High-Speed CMOS Logic Octal D-Type Flip-Flop with Reset

February 1998 - Revised May 2003

Features

- Common Clock and Asynchronous Master Reset
- Positive Edge Triggering
- · Buffered Inputs
- Fanout (Over Temperature Range)
 - Standard Outputs......10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC273 and 'HCT273 high speed octal D-Type flip-flops with a direct clear input are manufactured with silicon-gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits.

Information at the D input is transferred to the Q outputs on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CP) and a common reset (\overline{MR}) . Resetting is accomplished by a low voltage level independent of the clock. All eight Q outputs are reset to a logic 0.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC273F3A	-55 to 125	20 Ld CERDIP
CD74HC273E	-55 to 125	20 Ld PDIP
CD74HC273M	-55 to 125	20 Ld SOIC
CD74HC273M96	-55 to 125	20 Ld SOIC
CD54HCT273F3A	-55 to 125	20 Ld CERDIP
CD74HCT273E	-55 to 125	20 Ld PDIP
CD74HCT273M	-55 to 125	20 Ld SOIC
CD74HCT273M96	-55 to 125	20 Ld SOIC

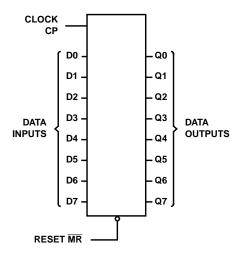
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

Pinout

(CERDIP) CD74HC273, CD74HCT273 (PDIP. SOIC) **TOP VIEW** MR 1 20 V_{CC} Q0 2 19 Q7 D0 3 18 D7 D1 17 D6 16 Q6 Q1 5 Q2 15 Q5 6 D2 14 D5 13 D4 D3 8 12 Q4 9 Q3 GND 10 11 CP

CD54HC273, CD54HCT273

Functional Diagram



TRUTH TABLE

	INPUTS								
RESET (MR)	CLOCK CP	DATA D _n	Q						
L	Х	Х	L						
Н	↑	Н	Н						
Н	↑	L	L						
Н	L	Х	Q ₀						

 $\label{eq:Hamiltonian} H = \mbox{High Voltage Level}, \ L = \mbox{Low Voltage Level}, \ X = \mbox{Don't Care}, \ \uparrow = \mbox{Transition from Low to High Level}, \ Q_0 = \mbox{Level Before the Indicated Steady-State Input Conditions Were Established}.$

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} 0.5V to 7V
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Drain Current, per Output, I _O
For -0.5V < V _O < V _{CC} + 0.5V
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$
DC V _{CC} or Ground Current, I _{CC}

Thermal Information

Thermal Resistance (Typical, Note 1) E (PDIP) Package	58 150 ⁰ C ⁰ C to 150 ⁰ C
Maximum Storage Temperature Range	_
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T _A
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES													
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V	
				6	4.2	1	-	4.2	-	4.2	-	V	
Low Level Input	V _{IL}	-	-	2	i	1	0.5	ı	0.5	-	0.5	٧	
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	1	-	1.9	-	1.9	-	٧	
Voltage CMOS Loads		V_{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
			-0.02	6	5.9	-	-	5.9	-	5.9	-	٧	
High Level Output	1			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧	
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V	
Voltage CMOS Loads		V_{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
omoo Loado			0.02	6	-	-	0.1	-	0.1	-	0.1	٧	
Low Level Output	1		4	4.5	-	-	0.26	-	0.33	-	0.4	V	
Voltage TTL Loads		5.2	6	ı	-	0.26	-	0.33	-	0.4	٧		
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ	
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μА	

DC Electrical Specifications (Continued)

		TE CONDI	ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	٧
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	l _l	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
MR	1.5
Data	0.4
СР	1.5

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360 μA max at $25^{o}C.$

Prerequisite For Switching Specifications

		TEST	TEST	v _{cc}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES												
Maximum Clock Frequency (Figure 1)	f _{MAX}	-	2	6	-	-	5	-	4	-	MHz	
			4.5	30	-	-	25	-	20	-	MHz	
			6	35	-	-	29	-	23	-	MHz	
MR Pulse Width (Figure 1)	t _W	-	2	60	-	-	75	-	90	-	ns	
			4.5	12	-	-	15	-	18	-	ns	
			6	10	-	-	13	-	15	-	ns	

^{2.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Prerequisite For Switching Specifications (Continued)

		TEST	ν _{cc}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Clock Pulse Width (Figure 1)	t _W	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Set-up Time Data to Clock (Figure 5)	t _{SU}	-	2	60	-	-	75	-	70	-	ns
			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns
Hold Time, Data to Clock (Figure 5)	t _H	-	2	3	-	-	3	-	3	-	ns
			4.5	3	-	-	3	-	3	-	ns
			6	3	-	-	3	-	3	-	ns
Removal Time, MR to Clock	t _{REM}	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	·	11	ı	13	-	ns
HCT TYPES											
Maximum Clock Frequency (Figure 2)	f _{MAX}	-	4.5	25	-	-	20	-	16	-	MHz
MR Pulse Width (Figure 2)	t _w	-	4.5	12	-	-	15	-	18	-	ns
Clock Pulse Width (Figure 2)	t _w	-	4.5	20	-	-	25	-	30	-	ns
Set-up Time Data to Clock (Figure 6)	tsu	-	4.5	12	-	-	15	-	18	-	ns
Hold Time, Data to Clock (Figure 6)	tH	-	4.5	3	-	-	3	-	3	-	ns
Removal Time, MR to Clock	t _{REM}	-	4.5	10	-	-	13	-	15	-	ns

Switching Specifications Input t_r , $t_f = 6 \text{ns}$

		TEST		25°C		-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay, Clock to Output (Figure 3)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	150	190	225	ns
			4.5	-	30	38	45	ns
			6	-	26	30	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay,	t _{PHL}	C _L = 50pF	2	-	150	190	225	ns
MR to Output (Figure 3)			4.5	-	30	38	45	ns
			6	-	26	30	38	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	75	95	110	ns
(Figure 3)			4.5	-	15	19	22	ns
			6	-	13	16	19	ns
Input Capacitance	C _I	-	-	-	10	10	10	pF
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	60	-	-	-	MHz

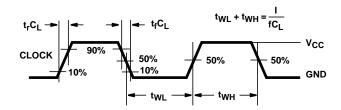
Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

				25°C		-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	TEST	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	25	-	-	-	pF
HCT TYPES								
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	30	38	45	ns
Clock to Output (Figure 4)		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay, MR to Output (Figure 4)	t _{PHL}	C _L = 50pF	4.5	-	32	40	48	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	15	19	22	ns
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	50	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	25	-	-	-	pF

NOTES:

- 3. C_{PD} is used to determine the dynamic power consumption, per flip-flop.
- P_D = C_{PD} V_{CC}² f_i + ∑ (C_L V_{CC}² + f_O) where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

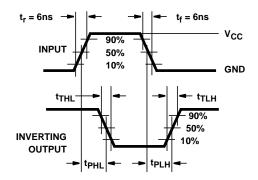
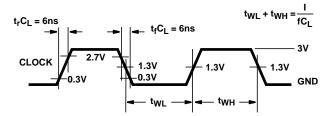


FIGURE 3. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

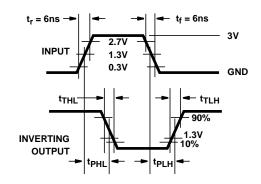


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

Test Circuits and Waveforms (Continued)

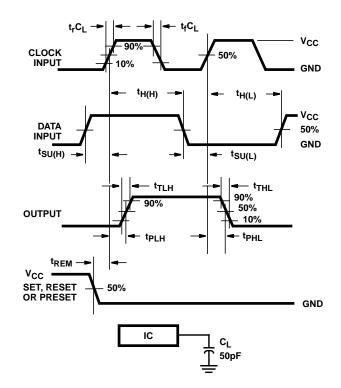


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

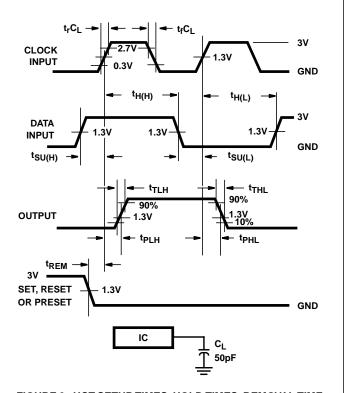


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS





9-May-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
5962-8772501RA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A	Sampl
CD54HC273F	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC273F	Sampl
CD54HC273F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	8409901RA CD54HC273F3A	Sampl
CD54HCT273F	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HCT273F	Sampl
CD54HCT273F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A	Sampl
CD74HC273E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC273E	Samp
CD74HC273EE4	ACTIVE	PDIP	N	20		TBD	Call TI	Call TI	-55 to 125	CD74HC273E	Samp
CD74HC273M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM -55 to 125		HC273M	Samp
CD74HC273M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samp
CD74HC273M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samp
CD74HC273M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samp
CD74HC273ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samp
CD74HC273MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samp
CD74HCT273E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT273E	Samp
CD74HCT273EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT273E	Samp
CD74HCT273M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT273M	Samp
CD74HCT273M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT273M	Samp
CD74HCT273M96E4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI	-55 to 125	HCT273M	Samp



PACKAGE OPTION ADDENDUM

9-May-2014

Orderable Device	Status	Package Type		Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HCT273M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT273M	Samples
CD74HCT273ME4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI	-55 to 125	HCT273M	Samples
CD74HCT273MG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI	-55 to 125	HCT273M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

9-May-2014

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC273, CD54HCT273, CD74HC273, CD74HCT273:

Military: CD54HC273, CD54HCT273

NOTE: Qualified Version Definitions:

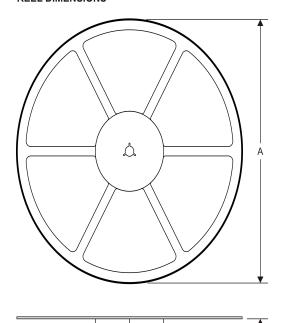
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

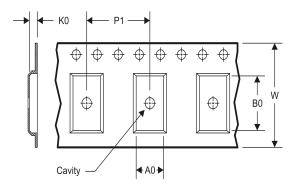
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TAPE AND REEL INFORMATION

REEL DIMENSIONS







A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC273M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT273M96	SOIC	DW	20	2000	367.0	367.0	45.0

14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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